

2SB1202S-E Datasheet



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DiGi Electronics Part Number	2SB1202S-E-DG
Manufacturer	onsemi
Manufacturer Product Number	2SB1202S-E
Description	TRANS PNP 50V 3A TP
Detailed Description	Bipolar (BJT) Transistor PNP 50 V 3 A 150MHz 1 W Th rough Hole TP

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
2SB1202S-E	onsemi
Series:	Product Status:
	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
PNP	3 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
50 V	700mV @ 100mA, 2A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
1μΑ (ICBO)	140 @ 100mA, 2V
Power - Max:	Frequency - Transition:
1 W	150MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TO-251-3 Short Leads, IPak, TO-251AA	TP
Base Product Number:	
2SB1202	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	

Bipolar Transistor

(–)50 V, (–)3 A, Low V_{CE}(sat) (PNP)NPN Single TP/TP–FA

Features

- Adoption of FBET and MBIT Processes
- Large Current Capacitance and Wide ASO
- Low Collector to Emitter Saturation Voltage
- Fast Switching Speed
- Small and Slim Package Making it Easy to Make 2SB1202/2SD1802–used Sets Smaller
- These Devices are Pb-Free and are RoHS Compliant

Applications

• Voltage Regulators, Relay Drivers, Lamp Drivers, Electrical Equipment

ABSOLUTE MAXIMUM RATINGS at T_A = 25°C

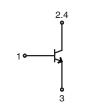
Parameter	Symbol	Conditions	Ratings	Unit
Collector to Base Voltage	V _{CBO}		(–)60	V
Collector to Emitter Voltage	V _{CEO}		(–)50	V
Emitter to Base Voltage	V _{EBO}		(–)6	V
Collector Current	۱ _C		(–)3	А
Collector Current (Pulse)	I _{CP}		(–)6	А
Collector Dissipation	P _C		1	W
		$T_C = 25^{\circ}C$	15	W
Junction Temperature	TJ		150	°C
Storage Temperature	T _{STG}		– 55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



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(For PNP, the polarity is reversed.)

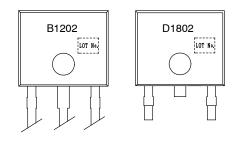




IPAK / TP CASE 369AJ

DPAK / TP-FA CASE 369AH

MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

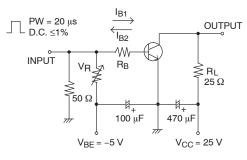
ELECTRICAL CHARACTERISTICS at $T_A = 25^{\circ}C$

			Ratings			l.
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector Cutoff Current	I _{CBO}	V_{CB} = (-)40 V, I _E = 0 A			(-)1	μA
Emitter Cutoff Current	I _{EBO}	$V_{EB} = (-)4V, I_{C} = 0 A$			(-)1	μA
DC Current Gain	h _{FE} 1	V _{CE} = (-)2 V, I _C = (-)100 mA	100*		560*	
	h _{FE} 2	V _{CE} = (-)2 V, I _C = (-)3 A	35			
Gain-Bandwidth Product	f _T	V _{CE} = (-)10 V, I _C = (-)50 mA		150		MHz
Output Capacitance	Cob	V _{CB} = (-)10 V, f = 1 MHz		(39)25		pF
Collector to Emitter Saturation Voltage	V _{CE} (sat)	I _C = (-)2 A, I _B = (-)100 mA		(-0.35)0.19	(-0.7)0.5	V
Base to Emitter Saturation Voltage	V _{BE} (sat)	V _{CE} = (-)2 V, I _C = (-)100 mA		(-)0.94	(-)1.2	V
Collector to Base Breakdown Voltage	V _{(BR)CBO}	I _C = (-)10 μA, I _E = 0 A	(-)60			V
Collector to Emitter Breakdown Voltage	V _{(BR)CEO}	I_{C} = (-)1 mA, R_{BE} = Ω	(-)50			V
Emitter to Base Breakdown Voltage	V _{(BR)EBO}	I _E = (-)10 μA, I _C = 0 A	(-)6			V
Turn–On Time	ton	See specified Test Circuit		70		ns
Storage Time	tstg	Circuit		(450)650		ns
Fall Time	tf	1		35		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. *The 2SB1202/2SD1802 are classified by 100 mA h_{FE} as follows :

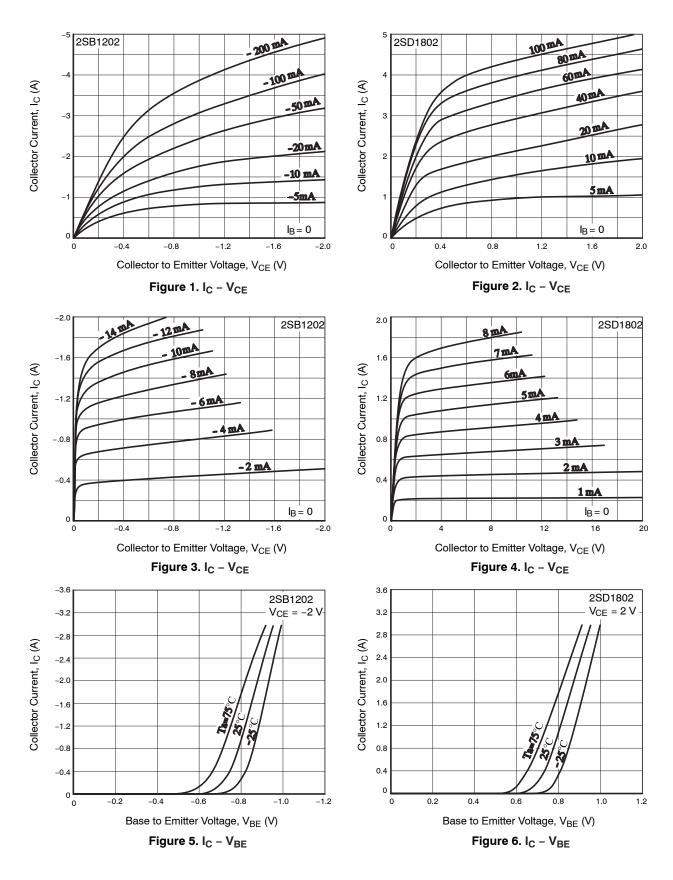
Rank	R	S	Т	U
h _{FE}	100 to 200	140 to 280	200 to 400	280 to 560

Switching Time Test Circuit

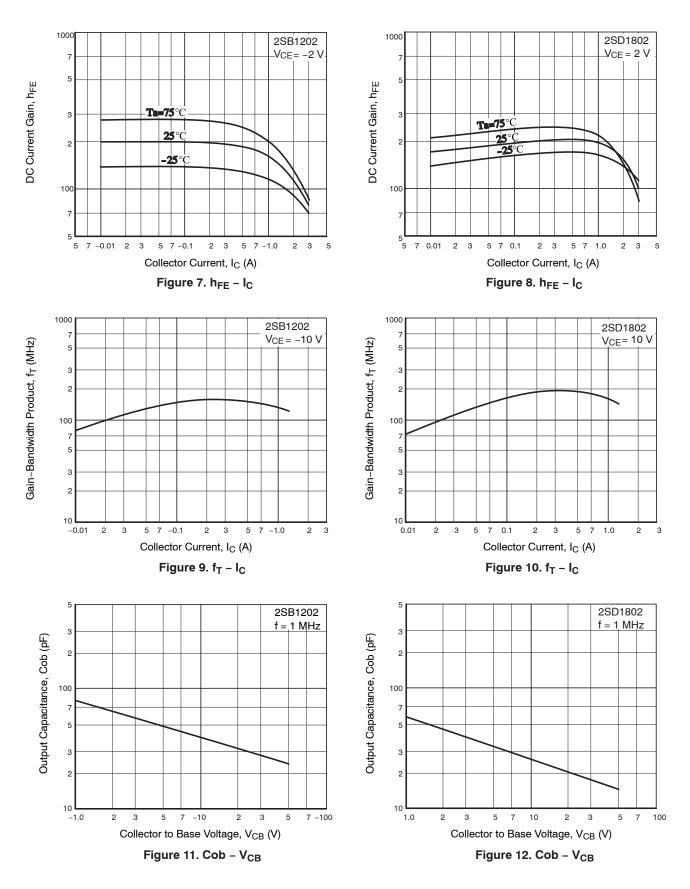


 I_C = 10 I_{B1} = -10 I_{B2} = 1 A For PNP, the polarity is reversed.

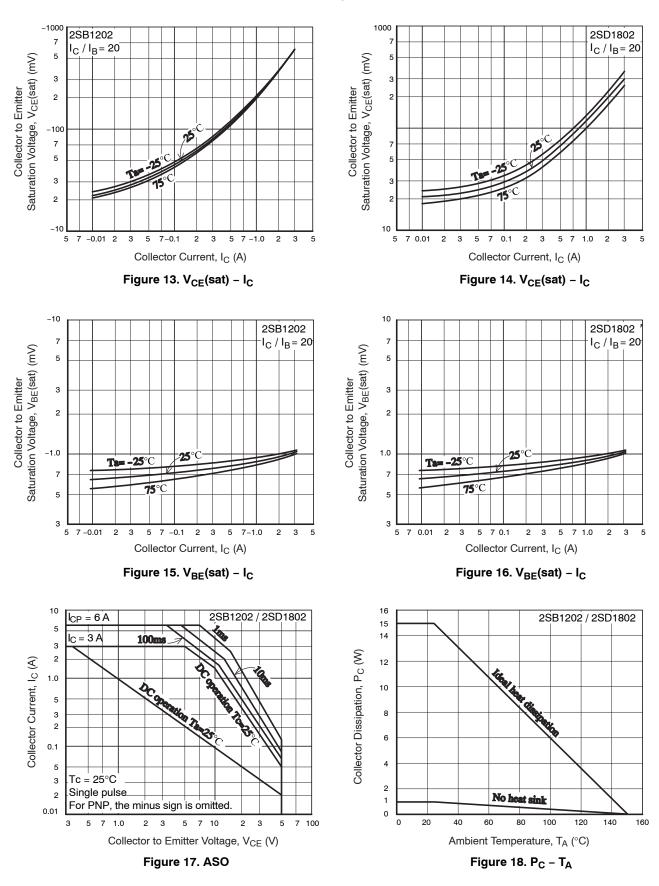
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)



2SB1202/2SD1802



ORDERING INFORMATION

Device	Package	Shipping†	memo
2SB1202S-E	TP	500pcs./bag	Pb-Free
2SB1202T-E	TP	500pcs./bag	
2SD1802S-E	TP	500pcs./bag	
2SD1802T-E	TP	500pcs./bag	
2SB1202S-TL-E	TP-FA	700pcs./reel	
2SB1202T-TL-E	TP-FA	700pcs./reel	
2SD1802S-TL-E	TP-FA	700pcs./reel	
2SD1802T-TL-E	TP-FA	700pcs./reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

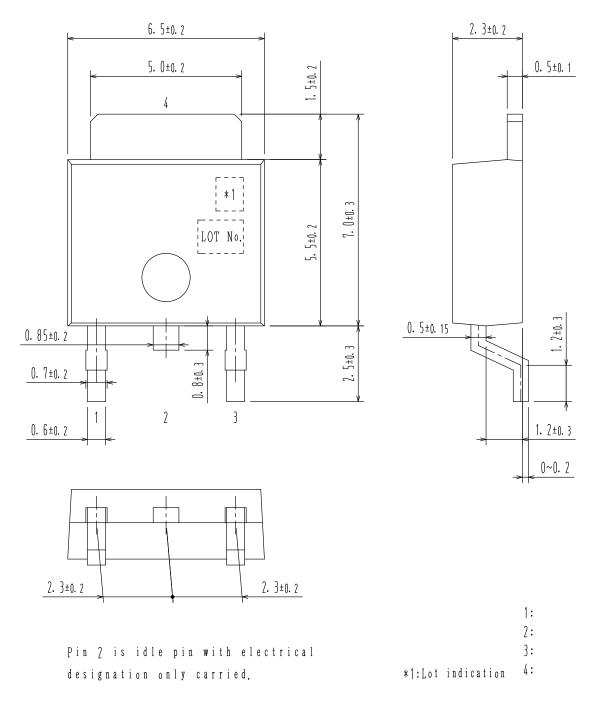


MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

DPAK / TP-FA CASE 369AH ISSUE O

DATE 30 JAN 2012



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DESCRIPTION:	DPAK / TP-FA		PAGE 1 OF 1

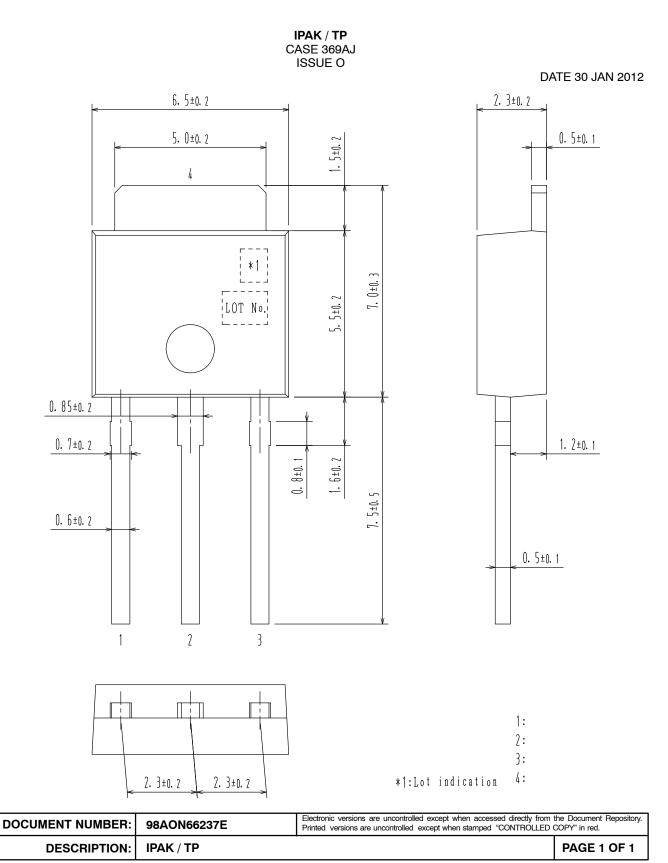
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



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